



United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231 www.uspto.gov

DATE MAILED: 12/06/2001

APPLICATION NO. FILING DATE		ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
09/665,920 09/2		9/20/2000 Belgacem Haba		RB1-008US	8524		
29150	7590	12/06/2001					
LEE & HA	•		EXAM	EXAMINER			
421 W. RIV SPOKANE,		AVE, STE 500 201		PHAN, T	PHAN, THANH S		
				ART UNIT	PAPER NUMBER		
			2841	2841			

Please find below and/or attached an Office communication concerning this application or proceeding.

					W
1		Application No.		Applicant(s)	<u> </u>
,	1,	09/665,920		HABA ET AL.	
Office Action Summa		xaminer		Art Unit	
•		Thanh S Phan		2841	
The MAILING DATE of this cor			sheet with the co		Idress
Period for Reply				•	
A SHORTENED STATUTORY PERI THE MAILING DATE OF THIS COM - Extensions of time may be available under the pre after SIX (6) MONTHS from the mailing date of th - If the period for reply specified above is less than - If NO period for reply is specified above, the maxi - Failure to reply within the set or extended period of - Any reply received by the Office later than three n eamed patent term adjustment. See 37 CFR 1.70 Status	MUNICATION. ovisions of 37 CFR 1.136(a is communication. thirty (30) days, a reply will imum statutory period will a for reply will, by statute, canonths after the mailing da	a). In no event, howeverthin the statutory mining apply and will expire Suse the application to	ver, may a reply be time mum of thirty (30) days SIX (6) MONTHS from to become ABANDONED	ely filed will be considered time he mailing date of this o	ly. ommunication.
1) Responsive to communication	n(s) filed on	. •			
2a) ☐ This action is FINAL .		action is non-fir	nal.		
3) Since this application is in corclosed in accordance with the	ndition for allowand practice under Ex	ce except for for c parte Quayle,	rmal matters, pro 1935 C.D. 11, 45	osecution as to the 53 O.G. 213.	ne merits is
Disposition of Claims					
4)⊠ Claim(s) <u>1-30</u> is/are pending i	n the application.				
4a) Of the above claim(s)	_ is/are withdrawn	from considera	ation.		
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1-30</u> is/are rejected.					
7) Claim(s) is/are objected	to.				
8) Claim(s) are subject to	restriction and/or e	election requirer	ment.		
Application Papers					
9) The specification is objected to	by the Examiner.				
10) The drawing(s) filed oni	s/are: a)⊡ accepte	d or b) Dobjecte	ed to by the Exan	niner.	
Applicant may not request that a					
11) The proposed drawing correction	on filed on is	s: a)∐ approve	d b) disappro	ved by the Examir	ner.
if approved, corrected drawings			ion.		
12) The oath or declaration is object	cted to by the Exan	niner.			
Priority under 35 U.S.C. §§ 119 and 12					
13) Acknowledgment is made of a	claim for foreign p	riority under 35	U.S.C. § 119(a))-(d) or (f).	
a) ☐ All b) ☐ Some * c) ☐ Non	e of:				
 Certified copies of the p 	riority documents h	nave been recei	ived.		
2. Certified copies of the p	=				
3. Copies of the certified c application from the * See the attached detailed Office	International Bure	au (PCT Rule 1	7.2(a)).		l Stage
14) Acknowledgment is made of a c					al application).
a) The translation of the fore	ign language provi	sional application	on has been rec	eived.	
Attachment(s)		. ,	50		
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Re 3) Information Disclosure Statement(s) (PTO-		4) 5) 6)	•	(PTO-413) Paper No Patent Application (P	

Art Unit: 2841

DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 4-6 are rejected under 35 U.S.C. 102(b) as being aniticipated by Wen (U.S Pat # 5,943,573).

Regarding claim 1. Wen discloses an apparatus (Figure 4D) comprising:
a substrate (reference 40) having a first elongated edge and a second elongated edge,
wherein the elongated edges are opposite one another; a plurality of channels
(references 43a, 43b) extending from the first elongated edge to the second elongated
edge, a plurality of memory devices disposed on the substrate; and wherein each of the
plurality of memory devices is coupled to one of the plurality of channels (Column 1,
lines 36-44).

Regarding claim 4. Wen discloses an apparatus as recited in claim 1 and further discloses wherein each channel includes a plurality of conductors, the plurality of conductors following a substantially linear path across the substrate (Column 5, line 55).

Art Unit: 2841

Regarding claim 5. Wen discloses an apparatus as recited in claim 1 wherein each channel includes a plurality of conductors, the plurality of conductors having lengths that are approximately equal (Figure 4d).

Regarding claim 6. An apparatus as recited in claim 1 wherein the substrate includes a plurality of electrical contacts along the first and second elongated edges (Figure 4d, edge portions of channels).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 2-3, are rejected under 35 U.S.C. 103(a) as being unpatentable over Wen (U.S Pat # 5,943,573).

Regarding claim 2. Wen discloses an apparatus as recited in claim 1 wherein the substrate has a first side and a second side except for the plurality of memory devices being disposed on both sides of the substrate. It would have been obvious to one of ordinary skill in the art at the time of the invention was made to disposed the plurality of

Art Unit: 2841

memory devices on both side of the substrate, since it was known in the art that usage of both sides of the substrate will result in a reduction of substrates used.

Regarding claim 3. Wen discloses an apparatus as recited in claim 1 wherein the substrate has a first side and a second side except for the plurality of channels extending across both sides of the substrate. It would have been obvious to one of ordinary skill in the art at the time of the invention was made to have the plurality of channels extending across both sides of the substrate, since it was know in the art that duplication of working parts on one side of the substrate to the second will result in a reduction of substrates used.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 7-30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Holman et al (U.S Pat # 6,005,776) in view of Wen (U.S Pat # 5,943,573).

Regarding claim 7. Holman et al. discloses an apparatus comprising:

a first substrate having a plurality of memory devices disposed thereon, and a second substrate having a plurality of memory devices disposed thereon; and a first connector

'Art Unit: 2841

A = 1 1 = 1 . OO 4 4

configured to couple the first channel portion to the second to channel portion, wherein the first connector includes a first slot that receives an edge of the first substrate and a second slot that receives an edge of the second substrate (Column 5, lines 7-16), but does not discloses a channel portion extending across the substrates. Wen teaches a substrate with a channel portion extending across the substrates. It would have been obvious to one of ordinary skill in the art at the time of the invention was made to modify Holman et al.'s with Wen's teachings to reduced breakdown voltage of the ROM device.

Regarding claim 8. Holman et al. and Wen disclose an apparatus as recited in claim 7. Holman et al. further discloses wherein the coupling of the first channel portion to the second channel portion through the connector forms a channel (Column 5, lines 7-16).

Regarding claims 9 and 10. Holman et al. and Wen disclose an apparatus as recited in claim 7. Wen further discloses wherein the channel portion extends from a first elongated edge of the substrate to a second elongated edge of the substrate (Figure 4d).

Regarding claims 11 and 12. Holman et al. and Wen disclose an apparatus as recited in claim 7. Wen further discloses wherein the channel portion includes a plurality of conductors following a substantially linear path across the substrate (Column 5, line 55).

Art Unit: 2841

Regarding claims 13 and 14. Holman et al. and Wen disclose an apparatus as recited in claim 7. Wen further discloses wherein the channel portion to includes a plurality of conductors having lengths that are approximately equal (Figure 4d).

Regarding claim 15. Holman et al. and Wen disclose an apparatus as recited in claim 7. Holman et al. further discloses a third substrate coupled to the first connector (Column 5, lines 8-9).

Regarding claim 16. Holman et al. and Wen disclose an apparatus as recited in claim 15. Wen further teaches a channel portion extending across the substrate (Figure 4d).

Regarding claim 17. Holman et al. and Wen disclose an apparatus as recited in claim 15 except for wherein the third substrate includes a third channel portion extending across the third substrate, the third channel portion including a plurality of conductors following a substantially linear path across the third substrate. It would have been obvious to one of ordinary skill in the art at the time of the invention was made to includes a third channel portion extending across the third substrate, the third channel portion including a plurality of conductors following a substantially linear path across the third substrate, since it has been held that mere duplication of the essential working parts of a device involves only routine skill in the art.

Art Unit: 2841

Regarding claim 18. Holman et al. and Wen disclose an apparatus as recited in claim 15. Wen further teaches wherein the substrate includes a channel portion extending across the substrate, the channel portion including a plurality of conductors having lengths that are approximately equal (Figure 4d).

Regarding claim 19. Holman et al. and Wen disclose an apparatus as recited in claim 7 except for a second connector having a first slot that receives an edge of the first substrate and a second slot that receives an edge of the second substrate, wherein the edges received by the second connector are on the opposite side of the substrates from the edges received by the first connector. It would have been obvious to one having ordinary skill in the art at the time the invention was made to include a second connector having a first slot that receives an edge of the first substrate and a second slot that receives an edge of the second substrate, since it has been held that mere duplication of the essential working parts of a device involves only routine skill in the art. St. Regis Paper Co. v. Bemis Co., 193 USPQ8.

Regarding claim 20. Holman et al. and Wen disclose an apparatus as recited in claim 19. Holman et al. further discloses wherein the connector is coupled to a motherboard (reference 610).

Regarding claims 21-23. Holman et al. and Wen disclose the limitations of the invention. See above claims.

Art Unit: 2841

Regarding claims 24-30. The methods steps are inherent since the limitations of the apparatus is disclosed.

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Yamaguchi (U.S Pat # 5,952,691) discloses a Non-Volatile Electrically Alterable Semiconductor Memory Device.

Yiu (U.S Pat # 5,117,389) discloses a Flat-Cell Read-Only Memory Integrated Circuit.

Bell (U.S Pat # 5,379,438) discloses a Transferring A Processing Units Data Between

Substrates In A Parallel Processor.

Yoon et al. (U.S Pat # 6,233,157) discloses a Printed Circuit Board And Method For Wiring Signal Lines On The Same.

Contacts information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thanh S Phan whose telephone number is 703-305-0069. The examiner can normally be reached on M-F 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Jeffrey Gaffin can be reached on 703-308-3301. The fax phone numbers for the organization where this application or proceeding is assigned are 703-305-7722 for regular communications and 703-305-7722 for After Final communications.

Application/Control Number: 09/665,920 Page 9

Art Unit: 2841

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

TSP December 2, 2001

> Jayprakash N. Gandhi Primary Examiner Technology Center 2800

J NRandh